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	Application No.	Applicant(s)
Notice of Allowability	09/885,319	STAN ET AL.
	Examiner	Art Unit
	Brian L. Mutschler	1753
The MAILING DATE of this communication apperature All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RI of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in or other appropriate commu GHTS. This application is st and MPEP 1308.	this application. If not included nication will be mailed in due course. THIS
1. This communication is responsive to <u>amendment filed Feb.</u>	ruary 9, 2004.	
2. A The allowed claim(s) is/are <u>1-5,8-13,16-23,26-34,37-39,43-</u>	-46,49,50 and 52.	
3. \boxtimes The drawings filed on <u>13 December 2001</u> are accepted by	the Examiner.	
4. ☐ Acknowledgment is made of a claim for foreign priority un a) ☐ All b) ☐ Some* c) ☐ None of the: 1. ☐ Certified copies of the priority documents have 2. ☐ Certified copies of the priority documents have 3. ☐ Copies of the certified copies of the priority documents have International Bureau (PCT Rule 17.2(a)). * Certified copies not received: Applicant has THREE MONTHS FROM THE "MAILING DATE" on the delow. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE. 5. ☐ A SUBSTITUTE OATH OR DECLARATION must be submit INFORMAL PATENT APPLICATION (PTO-152) which give for CORRECTED DRAWINGS (as "replacement sheets") mus (a) ☐ including changes required by the Notice of Draftspers 1) ☐ hereto or 2) ☐ to Paper No./Mail Date	been received. been received in Application cuments have been received of this communication to file ENT of this application. tted. Note the attached EXA is reason(s) why the oath or the submitted.	in this national stage application from the a reply complying with the requirements MINER'S AMENDMENT or NOTICE OF declaration is deficient.
(b) including changes required by the attached Examiner's Paper No./Mail Date Identifying indicia such as the application number (see 37 CFR 1. each sheet. Replacement sheet(s) should be labeled as such in the statement sheet in the statement sheet is should be labeled as such in the statement sheet.	84(c)) should be written on the	e drawings in the front (not the back) of
7. DEPOSIT OF and/or INFORMATION about the deposit attached Examiner's comment regarding REQUIREMENT I	sit of BIOLOGICAL MATE	RIAL must be submitted. Note the
 Attachment(s) 1. ☐ Notice of References Cited (PTO-892) 2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948) 3. ☑ Information Disclosure Statements (PTO-1449 or PTO/SB/0. Paper No./Mail Date 20030519 4. ☐ Examiner's Comment Regarding Requirement for Deposit of Biological Material 	6. ⊠ Interview Su Paper No./N 8), 7. ⊠ Examiner's A	ormal Patent Application (PTO-152) mmary (PTO-413), Mail Date <u>20040316</u> Amendment/Comment Statement of Reasons for Allowance

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EXAMINER'S AMENDMENT

1. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

Authorization for this examiner's amendment was given in a telephone interview with Mr. James Wu on March 16, 2004.

The application has been amended as follows:

In the claims:

- a. In claim 44 at line 5, please delete "of all".
- b. In claim 46 at line 4, please change "atomes" to --atoms--.
- 2. The following is an examiner's statement of reasons for allowance:

The instant claims are distinguished over the prior art of record because they provide a solar cell, a method for controlling the diffusion within a solar cell, and a method of fabricating a solar cell, where each provides a solar cell having both P atoms and As atoms as n-type dopants. The dopants are provided to create different regions within the solar cell, including a shallow diffusion region comprising mainly P atoms and a deeper diffusion region comprising mainly As atoms. The prior art of record does not teach or suggest the formation of the solar cell comprising a shallow n-type region containing mainly P atoms and a deep n-type region containing mainly As atoms. For

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example, Ermer et al. (U.S. Pat. No. 6,380,601) identify that P atoms diffuse more shallowly than As atoms, but desire only a shallow diffusion region. Wiesmann (U.S. Pat. No. 4,634,605) teaches that a combination of P and As can be used, but does not teach or suggest the formation of two diffusion regions. Stanbery (U.S. Pat. No. 4,322,571) does recognize the advantages of using both a shallow doped portion and a deep doped portion, but the solar cell and method uses only a single dopant type and achieves the result by shaping the substrate after doping takes place. There is no teaching or suggestion in the prior art to combine the references to create a solar cell having a shallow P doped region and a deep As doped region as claimed in the instant application. The instant invention provides a solar cell having two doped regions at different depths and different dopants and also provides a method for making such a cell utilizing the different diffusion rates of the dopant materials.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

3. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Brian L. Mutschler whose telephone number is (571) 272-1341. The examiner can normally be reached on Monday-Friday from 7:30am to 4:00pm.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nam Nguyen can be reached on (571) 272-1342. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

blm March 17, 2004 NAM NGUYEN PERVISORY PATENT EXAMINER

TECHNOLOGY CENTER 1700